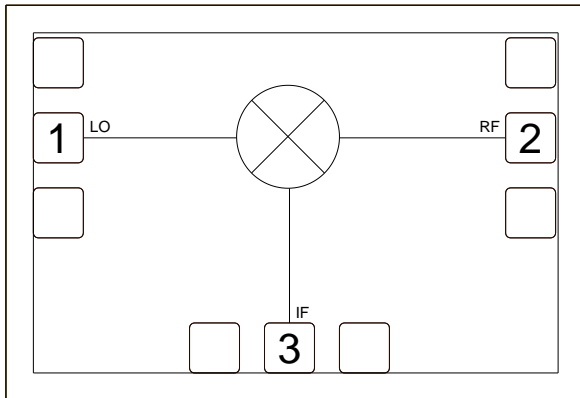


Product Overview

The CMD253 is a high IP3 double balanced mixer die that can be used for up- and downconverting applications between 6 and 14 GHz. The CMD253 has very high isolation to both the RF and IF ports due to the optimized balun structures, and can operate with an LO drive level as low as +15 dBm. The CMD253 can easily be configured as an image reject mixer or single sideband modulator with external hybrids and power splitters.

Functional Block Diagram



Key Features

- Low Conversion Loss
- High IP3
- High Isolation
- Wide IF Bandwidth
- Small Die Size: 1160 um x 790 um

Ordering Information

| Part No. | Description |
|----------|---|
| CMD253 | 6-14 GHz High IP3 Fundamental Mixer, 100 Piece Gel Pack |

Electrical Performance (IF = 100 MHz, LO = +19 dBm, T_A = 25 °C, F = 10 GHz)

| Parameter | Min | Typ | Max | Units |
|--------------------------|-----|--------|-----|-------|
| Frequency Range, RF & LO | | 6 - 14 | | GHz |
| Frequency Range, IF | DC | | 5 | GHz |
| Conversion Loss | | 6 | | dB |
| LO to RF Isolation | | 43 | | dB |
| LO to IF Isolation | | 39 | | dB |
| RF to IF Isolation | | 23 | | dB |
| Input P1dB | | 15 | | dBm |
| Input IP3 | | 23 | | dBm |

Unless otherwise noted, all measurements performed as a downconverter, IF = 100 MHz

Absolute Maximum Ratings

| Parameter | Rating |
|-----------------------------------|---------------|
| RF / IF Input Power | +25 dBm |
| LO Drive | +25 dBm |
| Operating Temperature | -40 to 85 °C |
| Storage Temperature | -55 to 150 °C |
| Thermal Resistance, θ_{JC} | 156 °C/W |
| Power Dissipation, P_{diss} | 417 mW |

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

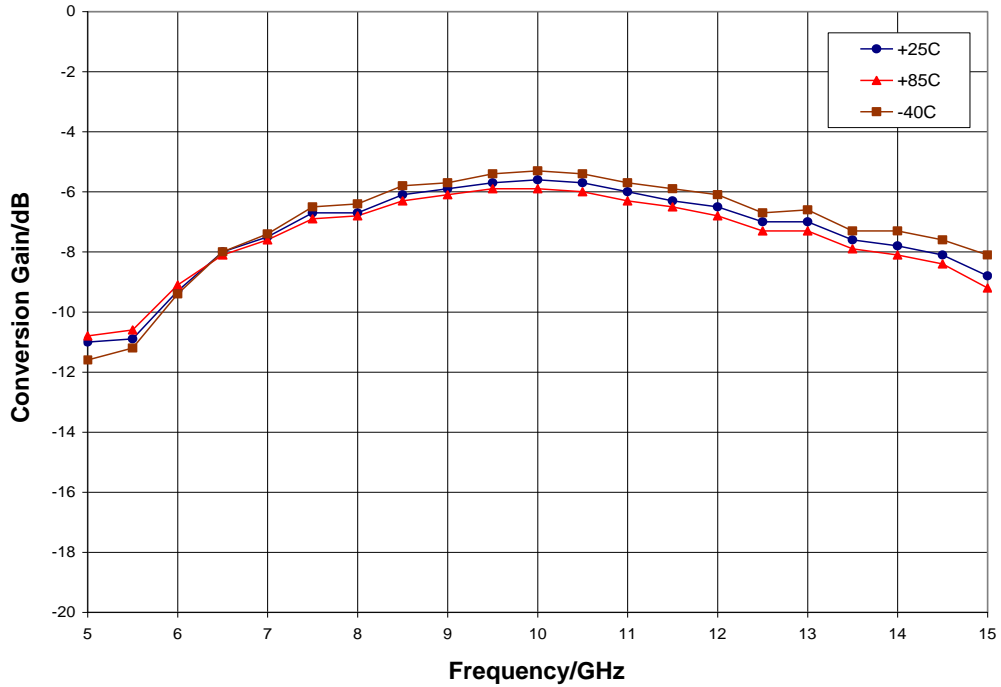
Electrical Specifications (IF = 100 MHz, LO = +19 dBm, $T_A = 25\text{ °C}$)

| Parameter | Min | Typ | Max | Min | Typ | Max | Units |
|--------------------------|-----|--------|-----|-----|--------|-----|-------|
| Frequency Range, RF & LO | | 8 - 12 | | | 6 - 14 | | GHz |
| Frequency Range, IF | DC | | 5 | DC | | 5 | GHz |
| Conversion Loss | | 6.5 | 8 | | 7 | 11 | dB |
| Noise Figure (SSB) | | 6.5 | | | 7 | | dB |
| LO to RF Isolation | 35 | 43 | | 32 | 43 | | dB |
| LO to IF Isolation | 29 | 39 | | 25 | 39 | | dB |
| RF to IF Isolation | 15 | 23 | | 12 | 23 | | dB |
| Input P1dB | | 15 | | | 15 | | dBm |
| Input IP3 | | 23 | | | 23 | | dBm |

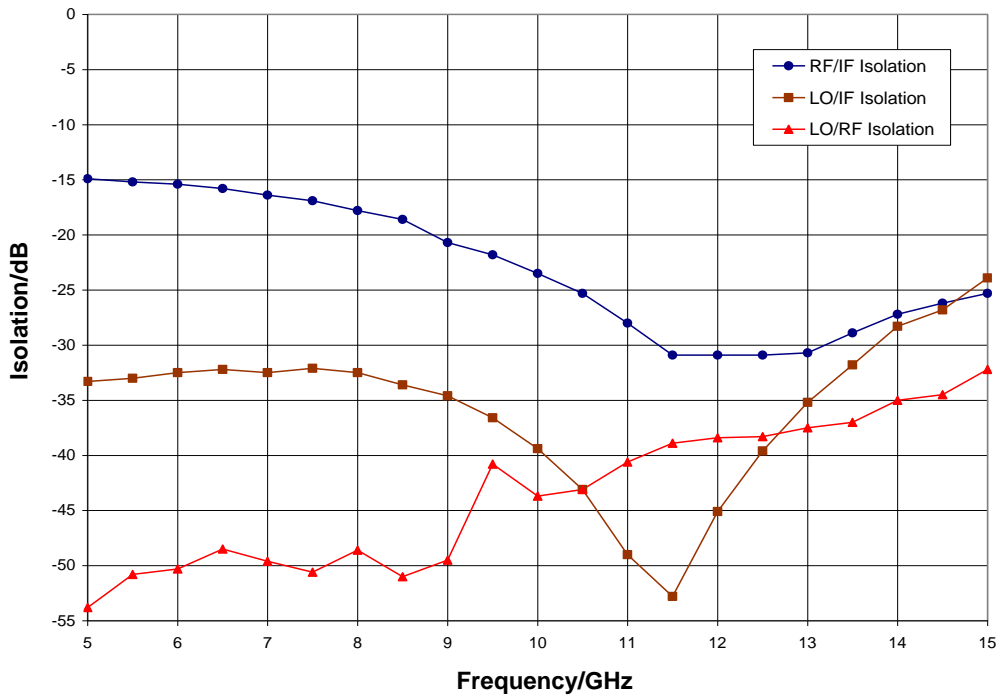
Unless otherwise noted, all measurements performed as a downconverter, IF = 100 MHz

Typical Performance

Conversion Gain vs. Temperature, LO = +19 dBm, IF = 100 MHz USB

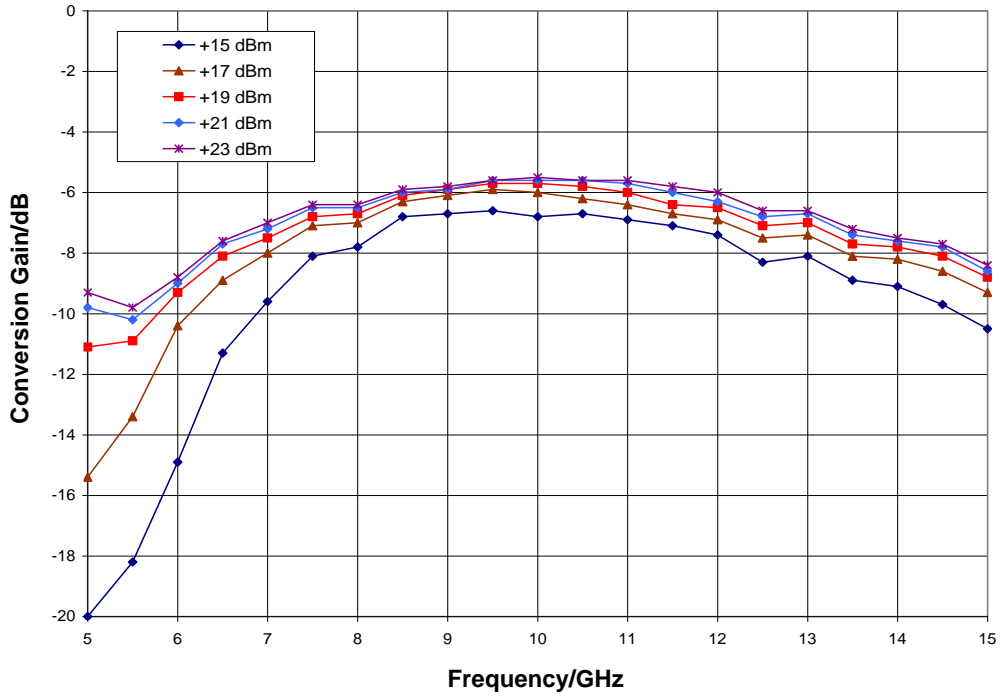


Isolation, LO = +19 dBm

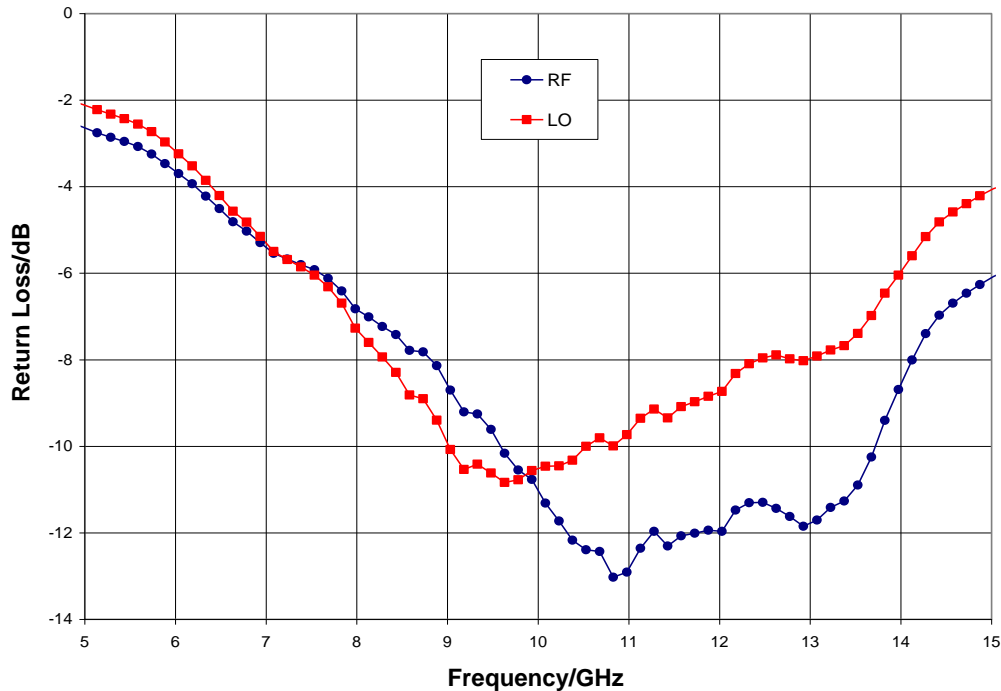


Typical Performance

Conversion Gain vs. LO Drive, IF = 100 MHz USB

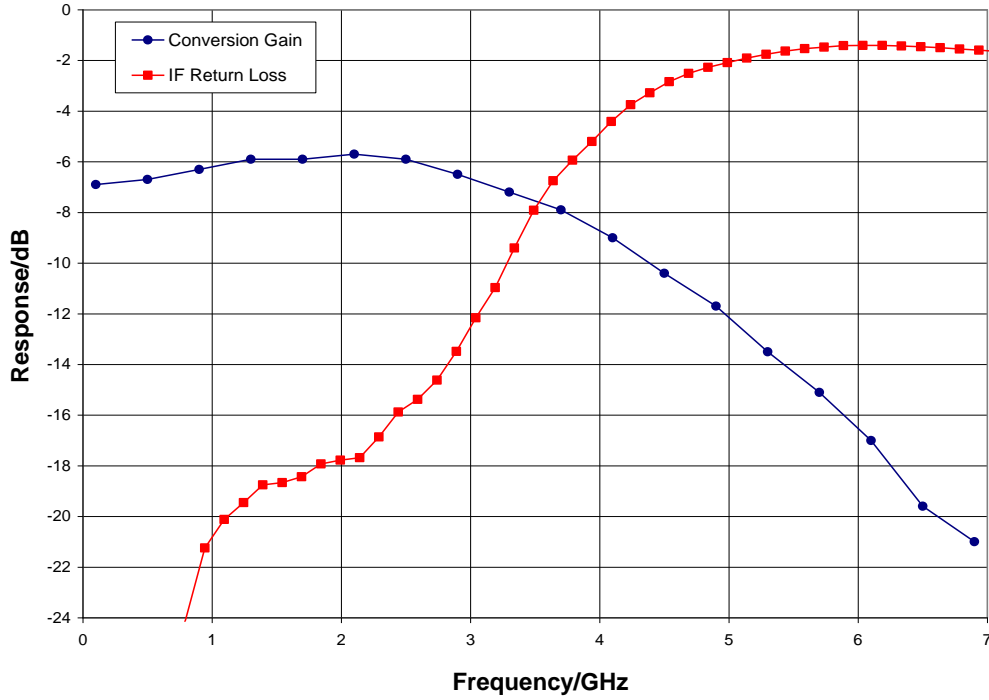


Return Loss, LO = +19 dBm

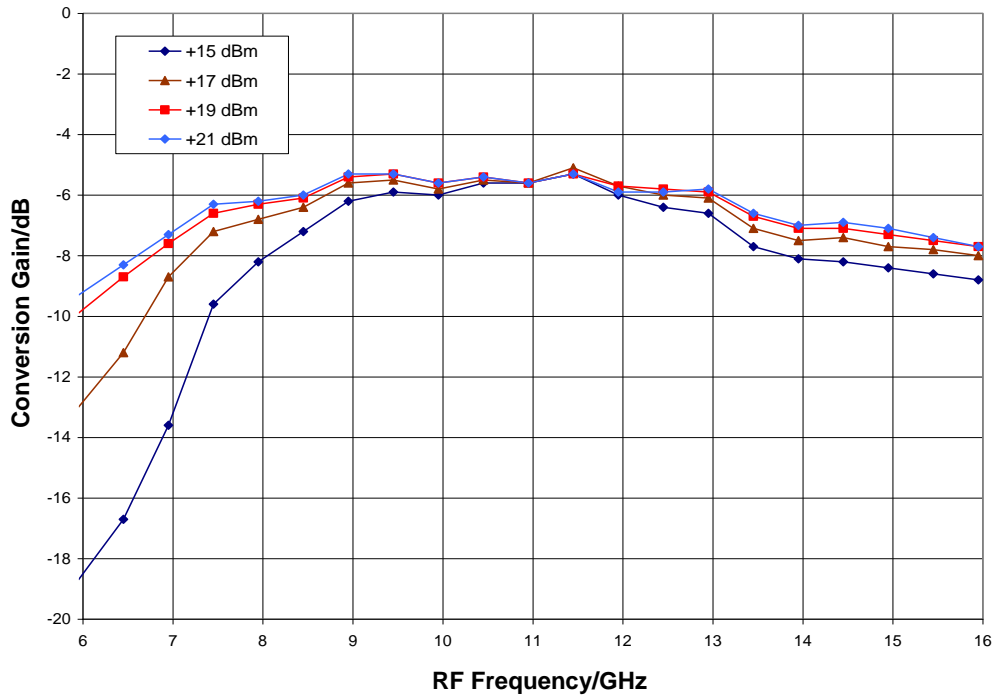


Typical Performance

IF Bandwidth, LO = +19 dBm

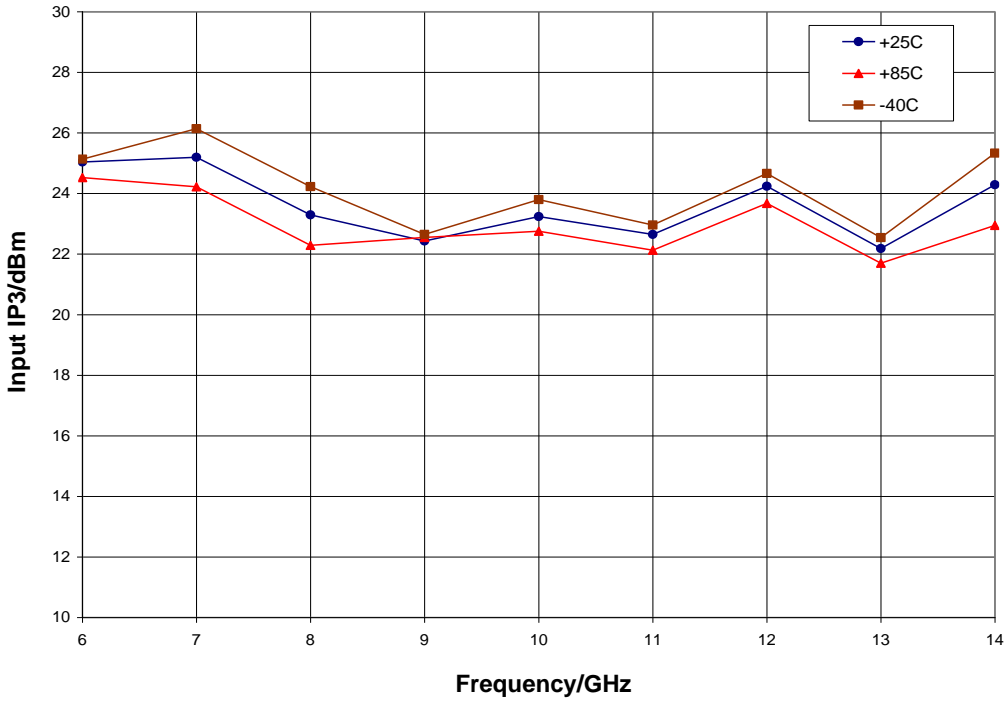


Upconverter Performance, Conversion Gain vs. LO Drive, IF input = 950 MHz

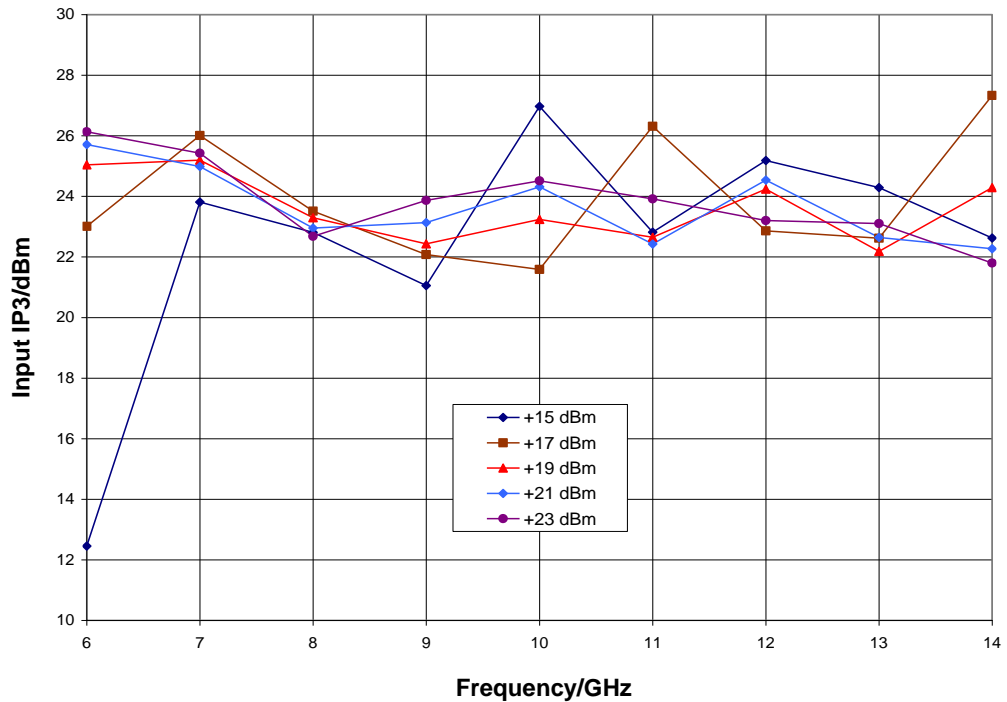


Typical Performance

Input IP3 vs. Temperature, LO = +19 dBm, IF = 100 MHz

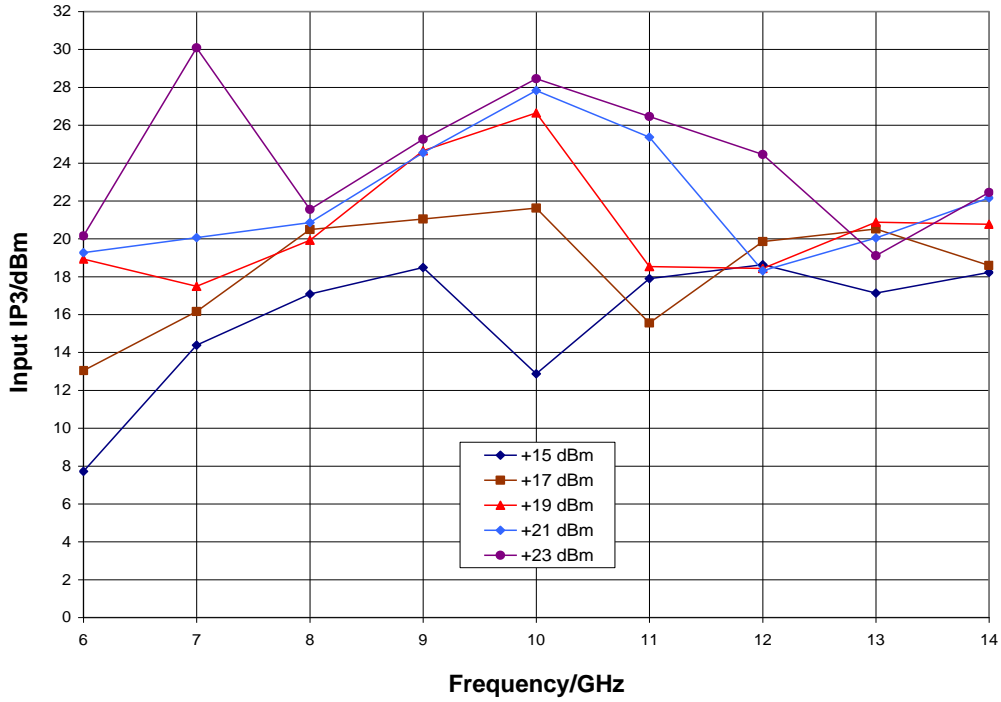


Input IP3 vs. LO Drive, IF = 100 MHz

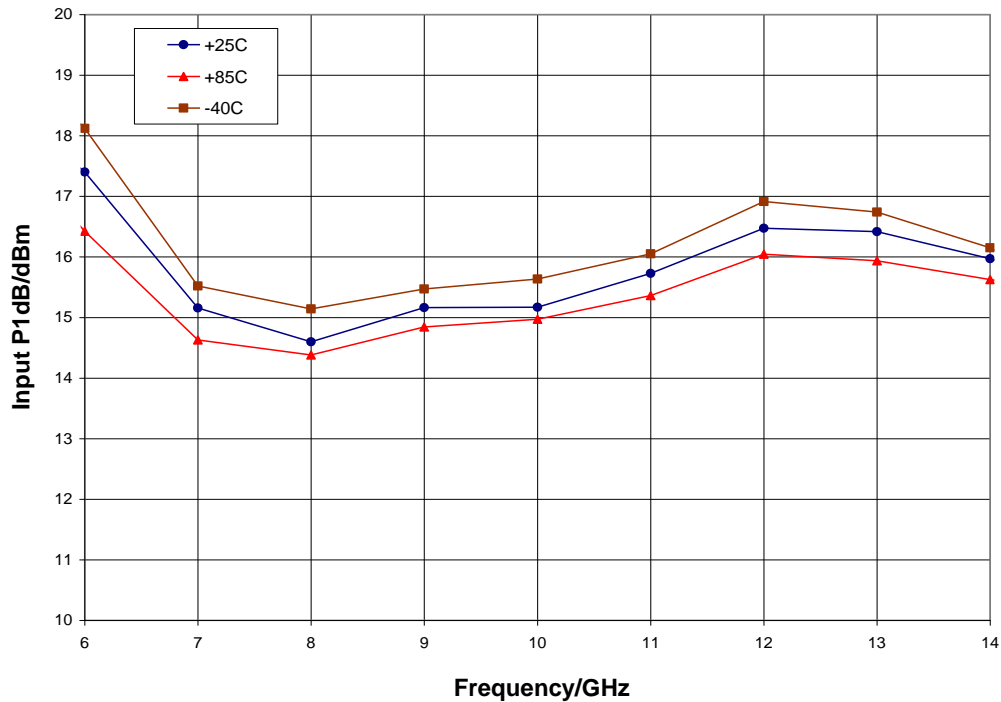


Typical Performance

Upconverter Performance, Input IP3 vs. LO Drive, IF = 100 MHz



Input P1dB vs. Temperature, LO = +19 dBm, IF = 100 MHz USB



Typical Performance

MxN Spurious Outputs

| mRF | nLO | | | | |
|-----|-----|-----|-----|-----|-----|
| | 0 | 1 | 2 | 3 | 4 |
| 0 | xx | 4 | 21 | 31 | 21 |
| 1 | 18 | 0 | 40 | 37 | 62 |
| 2 | >64 | >64 | >64 | >64 | >64 |
| 3 | >64 | >64 | >64 | >64 | >64 |
| 4 | | >64 | >64 | >64 | >64 |

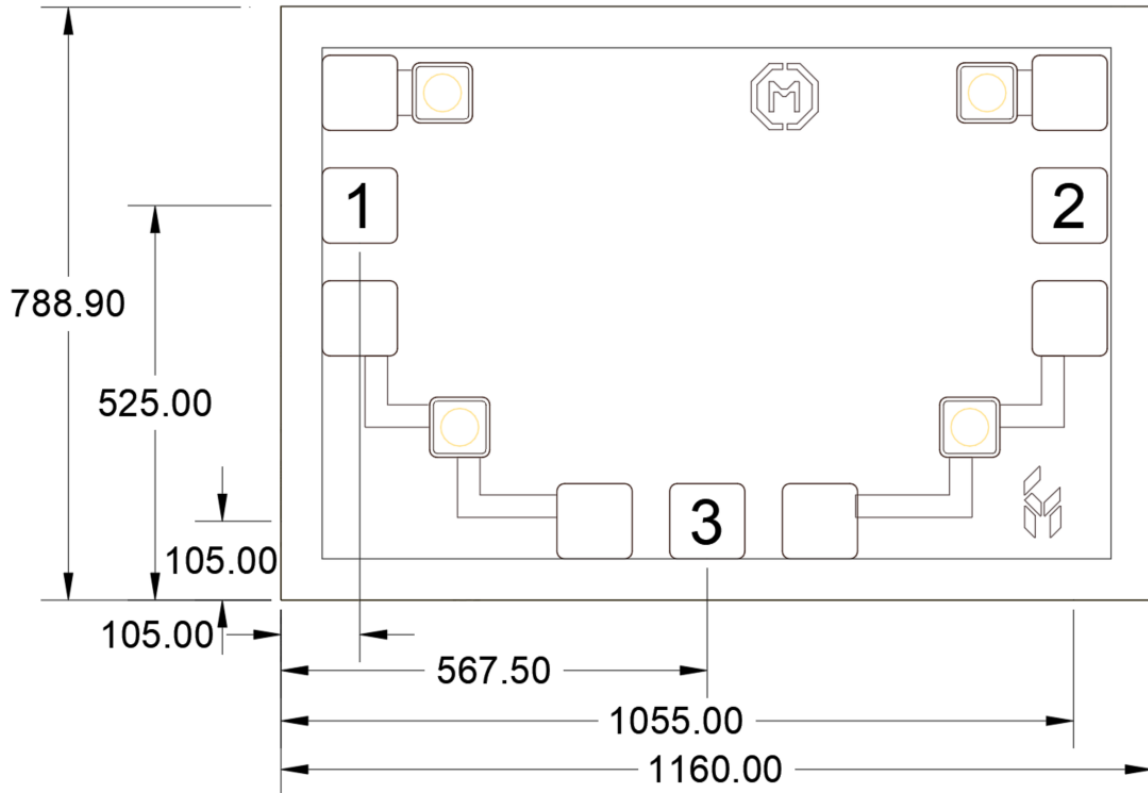
RF = 10.1 GHz @ -10 dBm

LO = 10.0 GHz @ +19 dBm

All values in dBc below the IF output power level (1RF - 1LO)

Mechanical Information

Die Outline (all dimensions in microns)

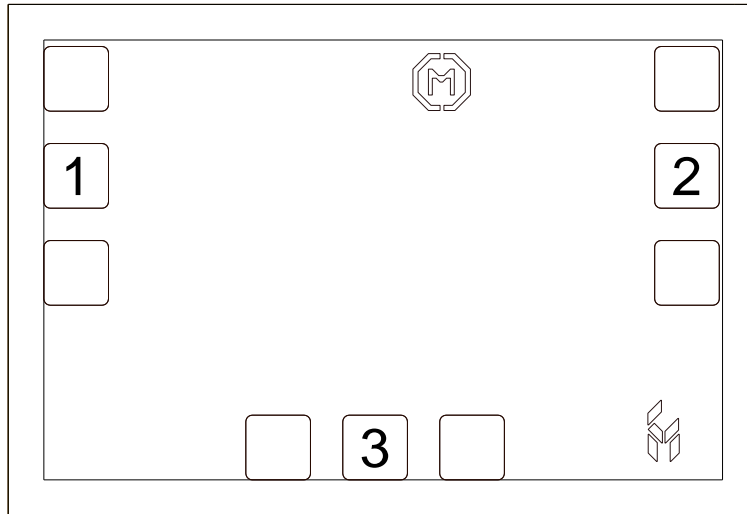


Notes:

1. No connection required for unlabeled pads
2. Backside is RF and DC ground
3. Backside and bond pad metal: Gold
4. Die is 100 microns thick
5. All bond pads (1, 2, 3) are 100 x 100 microns square

Pad Description

Pad Diagram



Functional Description

| Pin | Function | Description | Schematic |
|----------|----------|---|-----------|
| 1 | LO | This pin is DC coupled and matched to 50 ohms | |
| 2 | RF | This pin is DC coupled and matched to 50 ohms | |
| 3 | IF | This pin is DC coupled. For applications not requiring operation to DC, this port should be DC blocked using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC, this pin must not source or sink more than 16 mA of current or part non-function or part failure may result. | |
| Backside | Ground | Connect to RF / DC ground | |

Applications Information

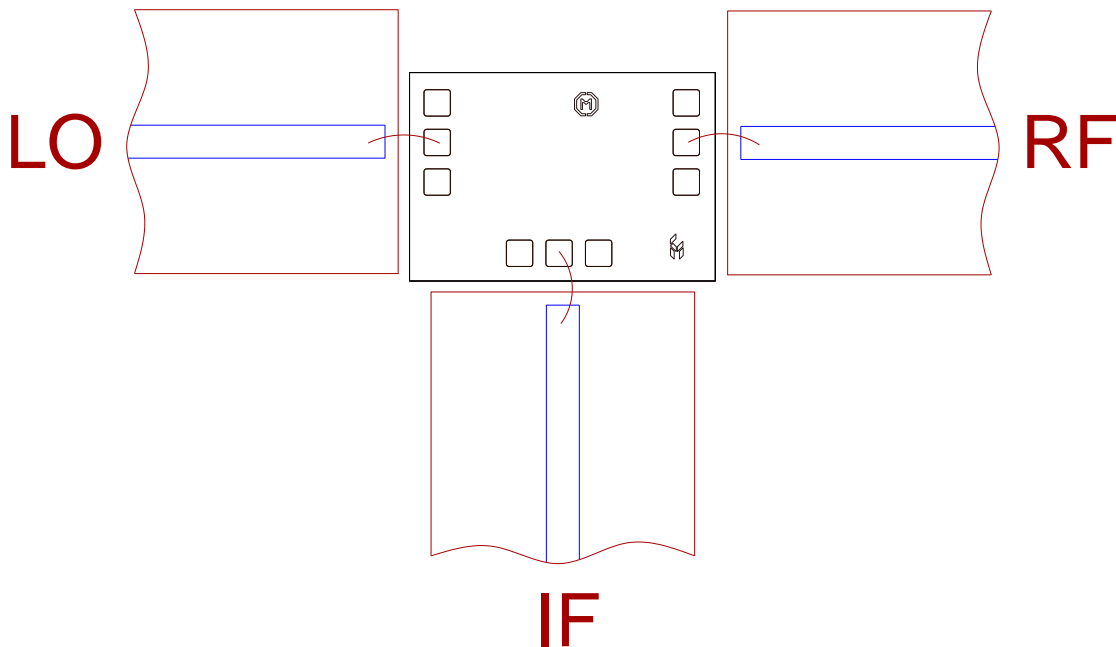
Assembly Guidelines

The backside of the CMD253 is RF ground. Die attach should be accomplished with electrically and thermally conductive epoxy only. Eutectic attach is not recommended. Standard assembly procedures should be followed for high frequency devices. The top surface of the semiconductor should be made planar to the adjacent RF transmission lines.

RF connections should be made as short as possible to reduce the inductive effect of the bond wire. Use of a 0.8 mil thermosonic wedge bonding is highly recommended as the loop height will be minimized.

The semiconductor is 100 um thick and should be handled by the sides of the die or with a custom collet. Do not make contact directly with the die surface as this will damage the monolithic circuitry. Handle with care.

Assembly Diagram



GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.

Handling Precautions

| Parameter | Rating | Standard |
|------------------------------|----------|--------------------------|
| ESD – Human Body Model (HBM) | Class 1A | ESDA / JEDEC JS-001-2012 |



Caution!
ESD-Sensitive Device

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- SVHC Free
- Halogen Free
- PFOS Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.qorvo.com

Tel: 1-844-890-8163

Email: customer.support@qorvo.com

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